ON Semiconductor[®]



ASM3P2760A

Peak EMI Reducing Solution

Features

- Generates an EMI optimized clock signal at the output.
- Integrated loop filter components.
- Operates with a 3.3V / 2.5V Supply.
- Operating current less than 4mA.
- CMOS design.
- Input frequency range: 6MHz to 12MHz for 2.5V. 6MHz to 13MHz for 3.3V.
- Generates a 1X low EMI spread spectrum clock of the input frequency.
- Frequency deviation: ±0.65% @ 8MHz.
- Available in 6L-TSOP (6L-TSOT-23) Package.

Product Description

The ASM3P2760A is a versatile spread spectrum frequency modulator designed specifically for a wide range of clock frequencies. The ASM3P2760A reduces electromagnetic interference (EMI) at the clock source, allowing system wide reduction of EMI of all clock dependent signals. The ASM3P2760A allows significant system cost savings by reducing the number of circuit board layers, ferrite beads and shielding that are traditionally required to pass EMI regulations.

Block Diagram

The ASM3P2760A uses the most efficient and optimized modulation profile approved by the FCC and is implemented by using a proprietary all digital method.

The ASM3P2760A modulates the output of a single PLL in order to "spread" the bandwidth of a synthesized clock, and more importantly, decreases the peak amplitudes of its harmonics. This results in significantly lower system EMI compared to the typical narrow band signal produced by oscillators and most frequency generators. Lowering EMI by increasing a signal's bandwidth is called 'spread spectrum clock generation.'

Applications

The ASM3P2760A is targeted towards all portable devices like MP3 players and digital still cameras.

Key Specifications

| Description | Specification |
|--------------------------|----------------------|
| Supply voltages | VDD = 3.3V / 2.5V |
| Cycle-to-Cycle Jitter | ±200pS (typ) |
| Output Duty Cycle | 45/55% |
| Modulation Rate Equation | F _{IN} /256 |
| Frequency Deviation | ±0.65% @ 8MHz |



Pin Configuration (6L-TSOP Package)



Pin Description

| Pin# | Pin Name | Туре | Description |
|------|-------------|------|--|
| 1 | PD | I | Power-down control pin. Pull low to enable power-down mode. Connect to VDD if not used. |
| 2 | XOUT | 0 | Crystal connection. If using an external reference, this pin must be left unconnected. |
| 3 | XIN / CLKIN | I | Crystal connection or external reference frequency input. This pin has dual functions. It can be connected either to an external crystal or an external reference clock. |
| 4 | VDD | Р | Power supply for the entire chip. |
| 5 | ModOUT | 0 | Spread spectrum clock output. |
| 6 | VSS | Р | Ground connection. |

Absolute Maximum Ratings

| Symbol | Parameter | Rating | Unit | | | | |
|----------------------|---|--------------|------|--|--|--|--|
| VDD, V _{IN} | Voltage on any pin with respect to Ground | -0.5 to +4.6 | V | | | | |
| T _{STG} | Storage temperature | -65 to +125 | C | | | | |
| Ts | Max. Soldering Temperature (10 sec) | 260 | C | | | | |
| TJ | Junction Temperature | 150 | C | | | | |
| T _{DV} | Static Discharge Voltage (As per JEDEC STD22- A114-B) | 2 | κv | | | | |
| | Note: These are stress ratings only and are not implied for functional use. Exposure to absolute maximum ratings for prolonged periods of time may affect device reliability. | | | | | | |

Operating Conditions

| Parameter | Description | Min | Max | Unit |
|-----------------|---|-------|-----|------|
| VDD | Supply Voltage | 2.375 | 3.6 | V |
| T _A | Operating Temperature (Ambient Temperature) | 0 | 70 | C |
| CL | Load Capacitance | | 15 | pF |
| C _{IN} | Input Capacitance | | 7 | pF |

| Symbol | Parameter | Min | Тур | Max | Unit |
|------------------|---|---------|-----|---------|------|
| VIL | Input low voltage | VSS-0.3 | | 0.8 | V |
| V _{IH} | Input high voltage | 2.0 | | VDD+0.3 | V |
| IIL | Input low current | | | -35 | μA |
| I _{IH} | Input high current | | | 35 | μA |
| I _{XOL} | XOUT output low current (@ 0.5V, VDD = 2.5V) | | 3 | | mA |
| I _{XOH} | XOUT output high current (@ 1.8V, VDD = 2.5V) | | 3 | | mA |
| V _{OL} | Output low voltage (VDD = 2.5V, I _{OL} = 8mA) | | | 0.6 | V |
| V _{OH} | Output high voltage (VDD = 2.5V, I _{OH} = 8mA) | 1.8 | | | V |
| I _{DD} | Static supply current ¹ | | | 10 | μA |
| Icc | Dynamic supply current (2.5V, 8MHz and no load) | | 2.5 | | mA |
| VDD | Operating Voltage | 2.375 | 2.5 | 2.625 | V |
| t _{on} | Power-up time (first locked cycle after power-up) ² | | | 5 | mS |
| ZOUT | Output impedance | | 50 | - | Ω |
| | / CLKIN pin and PD pin are pulled low. and XIN / CLKIN input are stable, PD pin is made high from low. | | | | · |

DC Electrical Characteristics for 2.5V Supply

AC Electrical Characteristics for 2.5V Supply

| Symbol | Para | Min | Тур | Max | Unit | |
|------------------------------|---|-------------------------|------|-------|------|-----|
| CLKIN | Input frequency | | 6 | | 12 | MHz |
| ModOUT | Output frequency | | 6 | | 12 | MHz |
| £ | Fraguency Deviation | Input Frequency = 6MHz | | ±1.0 | | % |
| f _d | Frequency Deviation Input Frequence | Input Frequency = 12MHz | | ±0.45 | | 70 |
| t _{LH} 1 | Output rise time (measured fr | 0.4 | 1.2 | 1.4 | nS | |
| t _{HL} 1 | Output fall time (measured fro | 0.4 | 0.9 | 1.1 | nS | |
| t _{JC} | Jitter (cycle-to-cycle) | | ±200 | | pS | |
| t _D | Output duty cycle | 45 | 50 | 55 | % | |
| Note: 1. t _{LH} and | t _{HL} are measured into a capacitive load | of 15pF. | • | | | - |

| Symbol | Parameter | Min | Тур | Max | Unit |
|------------------|---|---------|-----|---------|------|
| VIL | Input low voltage | VSS-0.3 | | 0.8 | V |
| V _{IH} | Input high voltage | 2.0 | | VDD+0.3 | V |
| IIL | Input low current | | | -35 | μA |
| I _{IH} | Input high current | | | 35 | μA |
| I _{XOL} | XOUT output low current (@ 0.4V, VDD = 3.3V) | | 3 | | mA |
| I _{XOH} | XOUT output high current (@ 2.5V, VDD = 3.3V) | | 3 | | mA |
| V _{OL} | Output low voltage (VDD = 3.3 V, I _{OL} = 8mA) | | | 0.4 | V |
| V _{OH} | Output high voltage (VDD = 3.3 V, I _{OH} = 8mA) | 2.5 | | | V |
| I _{DD} | Static supply current ¹ | | | 10 | μA |
| Icc | Dynamic supply current (3.3V, 8MHz and no load) | | 3.0 | | mA |
| VDD | Operating Voltage | 2.7 | 3.3 | 3.6 | V |
| t _{ON} | Power-up time (first locked cycle after power up) ² | | | 5 | mS |
| Zout | Output impedance | | 45 | | Ω |
| | / CLKIN pin and PD pin are pulled <u>lo</u> w. and XIN / CLKIN input are stable; PD pin is made high from low. | | | | · |

DC Electrical Characteristics for 3.3V Supply

AC Electrical Characteristics for 3.3V Supply

| Symbol | Pa | Parameter | | | Мах | Unit |
|--------------------------------------|---|---|----|------|-----|------|
| CLKIN | Input frequency | | 6 | | 13 | MHz |
| ModOUT | Output frequency | | 6 | | 13 | MHz |
| £ | Fragueney Deviation | Input Frequency = 6MHz | | ±1.0 | | % |
| f _d | Frequency Deviation | Frequency Deviation Input Frequency = 13MHz | | ±0.4 | | % |
| t _{LH} 1 | Output rise time (measure | Output rise time (measured at 0.8V to 2.0V) | | 1.3 | 1.5 | nS |
| t _{HL} 1 | Output fall time (measured | Output fall time (measured at 2.0V to 0.8V) | | | 1.2 | nS |
| t _{JC} | Jitter (cycle-to-cycle) | Jitter (cycle-to-cycle) | | | | pS |
| t _D | Output duty cycle | 45 | 50 | 55 | % | |
| Note: 1. t_{LH} and t_{HL} are m | easured into a capacitive load of 15pF. | | • | • | | • |

Typical Crystal Specifications

| Fundamental AT cut parallel resonant crystal | | | | |
|--|---------------------------|--|--|--|
| Nominal frequency | 8MHz | | | |
| Frequency tolerance | ± 50 ppm or better at 25℃ | | | |
| Operating temperature range | -25℃ to +85℃ | | | |
| Storage temperature | -40℃ to +85℃ | | | |
| Load capacitance(C _P) | 18pF | | | |
| Shunt capacitance | 7pF maximum | | | |
| ESR | 25 Ω | | | |

Note: Note: CL is Load Capacitance and Rx is used to prevent oscillations at overtone frequency of the Fundamental frequency.

Typical Crystal Interface Circuit



 $C_L = 2^* (C_P - C_S), \\ \text{Where } C_P = \text{Load capacitance of crystal}$

 C_{S} = Stray capacitance due to C_{IN} , PCB, Trace etc.

Typical Application Schematic



ASM3P2760A

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Package Information

6L-TSOP Package



| | Dimensions | | | | |
|--------|------------|-------|-----------|--------|--|
| Symbol | Inches | | Millim | neters | |
| | Min | Max | Min | Max | |
| А | | 0.04 | | 1.00 | |
| A1 | 0.00 | 0.004 | 0.00 | 0.10 | |
| A2 | 0.033 | 0.036 | 0.84 | 0.90 | |
| b | 0.012 | 0.02 | 0.30 | 0.50 | |
| Н | 0.005 | BSC | 0.127 | BSC | |
| D | 0.114 | BSC | 2.90 | BSC | |
| В | 0.06 | BSC | 1.60 | BSC | |
| е | 0.0374 BSC | | 0.950 BSC | | |
| С | 0.11 BSC | | 2.80 | BSC | |
| L | 0.0118 | 0.02 | 0.30 | 0.50 | |
| θ | 0° | 4° | 0° | 4° | |

Rev. 2 | Page 6 of 7 | www.onsemi.com

ASM3P2760A

Ordering Information

| Part Number | Marking | Package Type | Temperature |
|------------------|---------|--|-------------|
| ASM3P2760AF-06OR | E4L | 6L-TSOP(6L-TSOT-23), TAPE & REEL, Pb Free | 0℃ to +70℃ |

A "microdot" placed at the end of last row of marking or just below the last row toward the center of package indicates Pb-free.

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